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PATENT APPLICATION Docket No: 14321.71

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of)
	Kazuhide Kumakura et al.)
Serial No.:	10/532,782) Art Unit
Filing Date:	April 25, 2005) 2812
Confirmation No.:	6664)
For:	SUBSTRATE FOR NITRIDE SEMICONDUCTOR GROWTH)))

CERTIFICATE OF DEPOSIT UNDER 37 C.F.R. § 1.8

I hereby certify that the following documents are being deposited with the United States Postal Service as First Class Mail, postage prepaid, in an envelope addressed to: Commissioner for Patents, PO Box 1450, Alexandria, Virginia 22313-1450, on the 5th day of December 2005.

- Transmittal for Information Disclosure Statement (3 pages)
- Information Disclosure Statement (3 pages)
- Form PTO-1449 listing 8 references (2 pages)
- A copy of each of the references listed on the Form PTO-1449
- Postcard

Respectfully submitted,

DANA L. TANGREN Attorney for Applicant

Registration No. 37,246

Customer No. 022913

Telephone No. 801.533.9800

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RICK D. NYDEGGER DEC 0 8 2005 BRENT P. LORIMEN
THOMAS R. VUKSINCK
LARRY R. LAYCOCK
JONATHAN W. RICHARDS
D WRIGHT BRENT P. LORIMER JOHN C. STRINGHAM JOHN M. GUYNN CHARLES L. ROBERTS DANA L. TANGREN ERIC L. MASCHOFF CHARLES J. VEVERKA ROBYN L. PHILLIPS RICHARD C. GILMORE * STERLING A. BRENNAN R. BURNS ISRAELSEN DAVID R. TODD DAVID B. DEILENBACH
L. DAVID GRIFFIN
ADDIAN I LEE Fraser D. Roy



CARL T. REED

R. Parrish Freeman, Jr. PETER F. MALEN, JR. L. REX SEARS, PH.D. WILLIAM R. RICHTER ROBERT E. AYCOCK JENS C. JENKINS MICHAEL B. DODD KEVIN W. STINGER WILLIAM J. ATHAY RYAN D. BENSON SARA D. JONES TIGE KELLER Janna L. Jensen MATTHEW D. TODD J. LaVar Oldham MICHAEL I. FRODSHAM Brett A. Hansen BRETT I. JOHNSON MATTHEW A. BARLOW Wesley C. Rosander ANDREW S. HANSEN CHAD E. NYDEGGER IOSEPH G. PIA CLINTON E. DUKE RYAN N. FARR * JAMES B. BELSHE KIRK R. HARRIS KEELY SCHNEITER MICHAEL M. BALLARD DAVID A. JONES SHANE K. JENSEN JONATHAN M. BENNS, PH.D.

VERNON R. RICE § OF COUNSEL

WORKMAN | NYDEGGER

INTELLECTUAL PROPERTY ATTORNEYS

1000 EAGLE GATE TOWER
60 EAST SOUTH TEMPLE
SALT LAKE CITY, UTAH 84111
TELEPHONE: (801) 533-9800
FAX: (801) 328-1707

WEBSITE: HTTP://www.wnlaw.com

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TRANSMITTAL FOR INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Transmitted herewith for filing and pursuant to 37 C.F.R. § 1.97 is an Information Disclosure Statement, which includes the following statements, if any, required variously by 37 C.F.R. § 1.98:

<u>X</u>	Statement of relevance of selected cited references not in the English language which are not translated.
	Statement that selected cited references are substantially cumulative of an enclosed or previously submitted reference.
	Statement that selected cited references were previously cited by or

statement that selected cited references were previously cited by or submitted to the United States Patent and Trademark Office in a prior application which is relied upon for an earlier filing date under 35 U.S.C. § 120.

Additional Materials Required Due to Content of Information Disclosure Statement A. Transmitted are the following documents in addition to the Information Disclosure Statement as required variously under 37 C.F.R. § 1.98: \mathbf{X} Form PTO-1449 listing 8 reference submitted for consideration. X A copy of the non-US references listed on the Form PTO-1449. English translations of () of the references listed on the Form PTO-1449 which are not in the English language. Copies of the following documents from the prosecution of a previous, related application: Form PTO-1449 AND INFORMATION DISCLOSURE STATEMENT; and Form PTO-892 B. Additional Materials Required Due to Timing of Filing of Information Disclosure Statement The transmitted Information Disclosure Statement is being filed within one (1) of the following four (4) time periods: I. X Prior to the later of either three (3) months following the filing date or the mailing of a first Office Action. Accordingly, no materials other than those listed above are enclosed. II. Following the latter of either three (3) months following the filing date or the mailing of a first Office Action, but before the mailing of a final Office Action or a Notice of Allowance. Accordingly, to secure consideration thereof, one (1) of the following is also enclosed: Promptness Certification; or in the amount of constituting the submission fee set forth in 37 C.F.R. § 1.17(p). III. After the mailing of a Notice of Allowance, but before payment of the Issue Fee. Accordingly, in order to secure consideration thereof, each of the following are also enclosed: Promptness Certificate:

Petition for Consideration; and

			Check No. in the amount of constituting the petition fee set forth in 37 C.F.R. § 1.17(i)(1).	
	IV.		After payment of the Issue Fee. Accordingly, in order to secure consideration thereof, each of the following are also enclosed:	
			Petition to Withdraw from Issue; and	
			Check No in the amount of constituting the petition fee set forth in 37 C.F.R. § 1.17(i)(1).	
	C.	<u>Fees</u>		
The Commissioner is hereby authorized to charge payment of or any deficiency in the following fees associated with this communication, or to credit any overpayment thereof, to Deposit Account No. 23-3178. A duplicate copy of this letter is enclosed.				
	<u>X</u>	Any fee required in relation to filing of this letter or any documents transmitted therewith.		
	_	The submission fee set forth in 37 C.F.R. § 1.17(p) in the event that 37 C.F.R. § 1.97(c) applies and the Examiner is not satisfied that any Promptness Certificate submitted meets the requirements of 37 C.F.R. § 1.97(e).		
		The su	abmission fee set forth in 37 C.F.R. § 1.17(p).	
		The pe	etition fee set forth in 37 C.F.R. § 1.17(i)(1).	
	Dated	this 5 th	day of December 2005.	
			Respectfully submitted	

Respectfully submitted

DANA L. TANGREN Attorney for Applicant Registration No. 37,246 Customer No. 022913

Telephone No. 801.533.9800

DLT:dfw Enclosures DFW0000016310V001.doc Form PTO-1449

Applicant: Serial Nd. P E

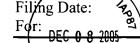
Kazuhide Kumakura et al.

10/532,782

April 25, 2005

Sheet 1 of 2 Confirmation No.: 6664 Att'y Docket No.: 14321.71

Art Unit: 2812



SUBSTRATE FOR NITRIDE SEMICONDUCTOR GROWTH

INFORMATION DISCLOSURE CITATIONS MADE BY APPLICANT

U.S. Patent Documents

		U.S. Patent Document	<u>S</u>		
Examiner <u>Initial*</u>	Document Number	Issue <u>Date</u>	<u>Name</u>	<u>Name</u>	
		Foreign Patent Documen	<u>nts</u>		
Examiner <u>Initial</u> *	Document Number	PublicationDate	Country or Patent Office	Translation	
1	02-141495	05/30/1990	Japan	No	
2	11-060395	03/02/1999	Japan	No	
3	11-340147	12/10/1999	Japan	No	
4	WO 02/12598 A1	02/14/2002	PCT	N/A	
Examiner Initial*		Effects of Reactive Ion Bean of GaN Films, Journal of A	, ii	3	
6	2000, pp. 7940-7945. Cyril Pernot et al., Low-Intensity Ultraviolet Photodetectors Based on AlGaN, Japanese Journal Applied Physics, Vol. 38, 1999, pp. L487-L489.				
7	H. Amano et al., Metalorganic Vapor Phase Epitaxial Growth of a High Quality GaN Film Using an AIN Buffer Layer, Applied Physics Letters, Vol. 48, No. 5, February 3, 1986, pp. 353-355.				
8	Shuji Nakamura, GaN Growth Using GaN Buffer Layer, Japanese Journal of Applied Physics, Vol. 30, No. 10A, October 1991, pp. L1705-L1707.				
Examiner:		Date Considere	ed:		

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609, draw line through citation if

not in conformance and not considered. Include copy of this form with next communication to applicant.

Form PTO-1449

Kazuhide Kumakura et al.

Applicant: Serial No.:

10/532,782

Filing Date: For:

April 25, 2005

Att'y Docket No.: 14321.71 Art Unit: 2812

Confirmation No.: 6664

Sheet 2 of 2

SUBSTRATE FOR NITRIDE SEMICONDUCTOR GROWTH

References Cited by Applicants

While the filing of Information Disclosure Statements is voluntary, the procedure is governed by the guidelines of Section 609 of the Manual of Patent Examining Procedure and 37 C.F.R. §§ 1.97 and 1.98. To be considered a proper Information Disclosure Statement, Form PTO-1449 shall be accompanied by a copy of each listed patent or publication or other item of information and a translation of the pertinent portions of foreign documents (if an existing translation is readily available to the applicant), an explanation of relevance of each reference not in the English language, and should be submitted in a timely manner as set out in MPEP Sec. 609.

Examiners will consider all citations submitted in conformance with 37 C.F.R. § 1.98 and MPEP Sec. 609 and place their initials adjacent the citations in the spaces provided on this form. Examiners will also initial citations not in conformance with the guidelines which may have been considered. A reference may be considered by the Examiner for any reason whether or not the citation is in full conformance with the guidelines. A line will be drawn through a citation if it is not in conformance with the guidelines AND has not been considered. A copy of the submitted form, as reviewed by the Examiner, will be returned to the applicant with the next communication. The original of the form will be entered into the application file.

Each citation initialed by the Examiner will be printed on the issued patent in the same manner as references cited by the Examiner on Form PTO-892.

The reference designations "A1," "A2," etc. (referring to Applicant's reference 1, Applicant's reference 2, etc.) will be used by the Examiner in the same manner as Examiner's reference designations "A," "B," "C," etc. on Office Action Form PTO-1142.

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Examiner:	Date Considered:	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609, draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.